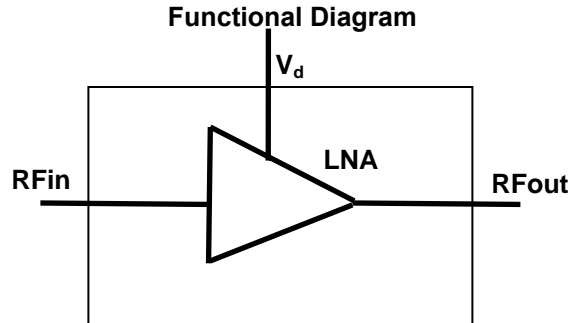


## 8.5 – 9.6 GHz Low Noise Amplifier Module

### Features

- ◆ Frequency Range: 8.5 – 9.6 GHz
- ◆ 1.5 dB Noise Figure
- ◆ 26.5 dB Gain
- ◆ 12 dBm P1dB
- ◆ Single supply operation +15 V
- ◆ Input Return Loss of 10 dB (Typ)
- ◆ Output Return Loss of 15 dB (Typ)
- ◆ Nominal Bias 80 mA @15V
- ◆ 0.15-um InGaAs pHEMT Technology
- ◆ Small form factor - 16mm x12mm x5 mm



### Typical Applications

- ◆ RADAR
- ◆ Military & space
- ◆ VSAT

### Description

The AMT2142021M is a connectorised LNA module operating in the 8.5 - 10.5 GHz frequency range. The LNA exhibits 26.5 dB of nominal gain and has a typical noise figure of 1.5 dB. The typical input return loss of the LNA is about 10 dB and the output return loss 15 dB. The nominal 1 dB compression point is 12 dBm.

The LNA features a small form factor of 16mm x 12mm x 5mm with field replaceable SMA connectors. The module can be conveniently used as a drop-in if required. The module operates from a single +15 V supply.

### Absolute Maximum Ratings <sup>(1)</sup>

Parameter	Absolute Maximum	Units
Drain bias voltage (Vd)	+16	volts
RF input power (RFin at Vd=15V)	+10	dBm
Operating temperature	-55 to +85	°C
Storage Temperature	-65 to +150	°C

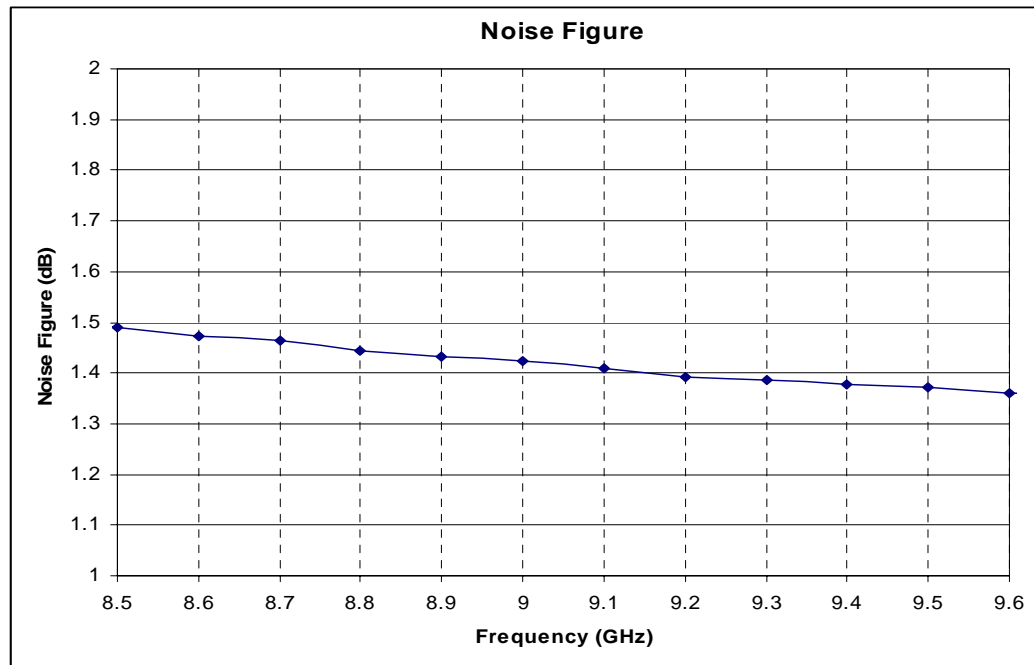
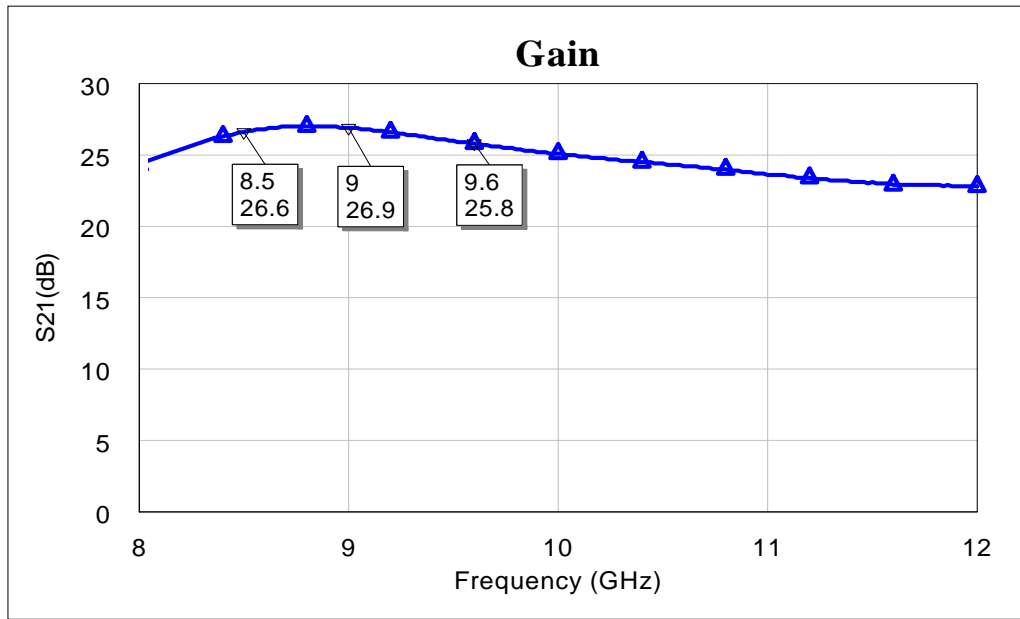
1. Operation beyond these limits may cause permanent damage to the component

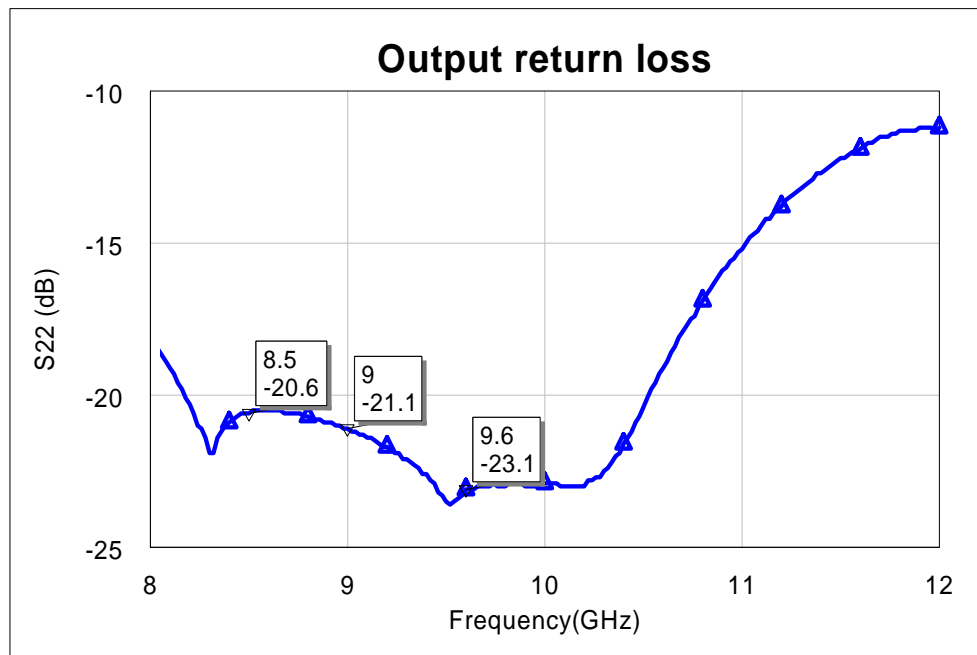
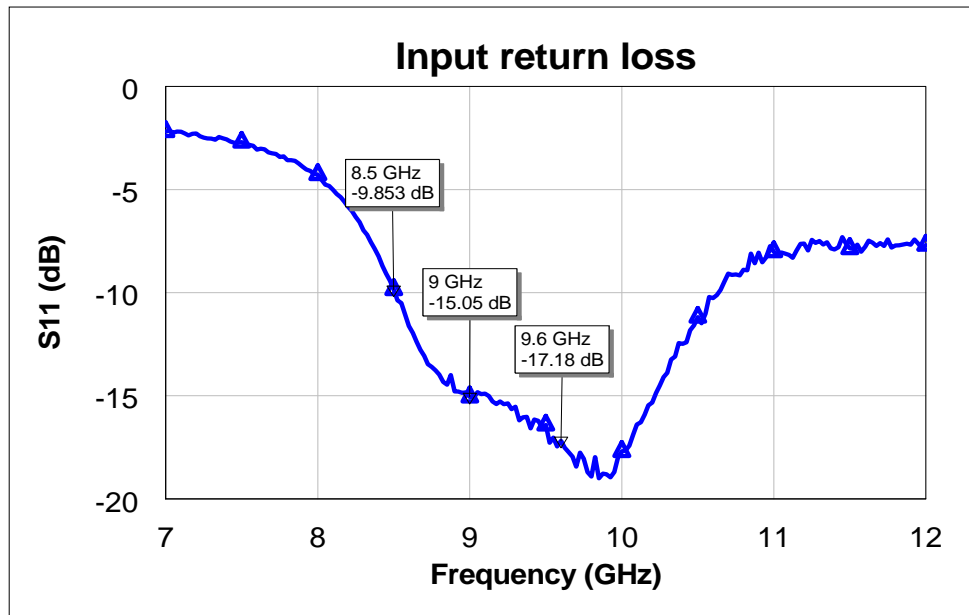
**Electrical Specifications @ T<sub>A</sub> = 25 °C, V<sub>d</sub> = +15V, Z<sub>o</sub> =50 Ω**

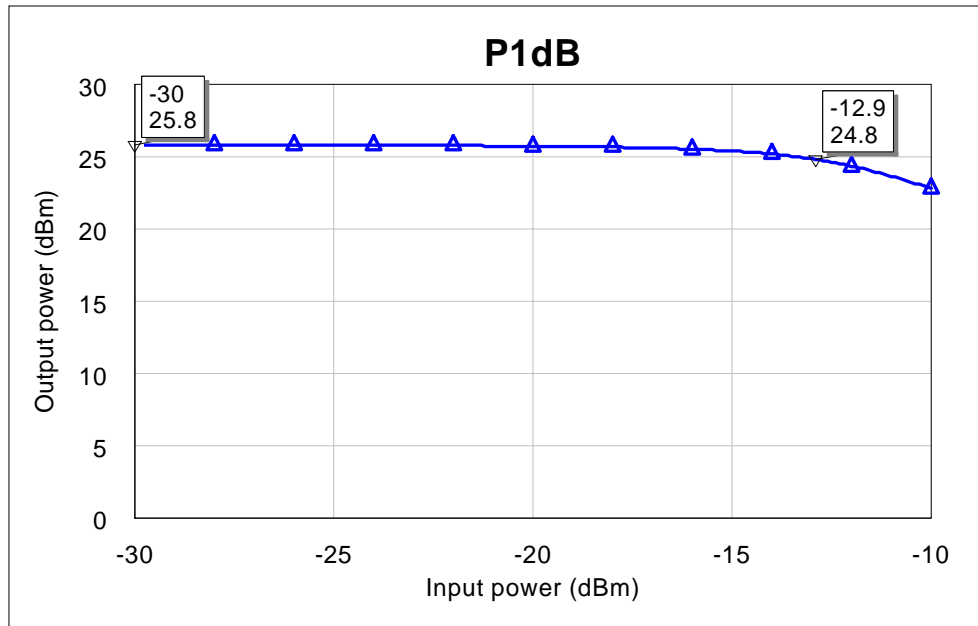
Parameter	Min.	Typ.	Max.	Units
Frequency Range	8.5	-	9.6	GHz
Gain	25	26.5	27	dB
Gain Flatness	-	±0.7	±1.0	dB
Noise Figure (max.)	-	1.5	-	dB
Input Return Loss	9	10	-	dB
Output Return Loss	12	15	-	dB
Output Power (P1dB)	10	12		dBm
Supply Current (I <sub>d</sub> )	70	80	100	mA

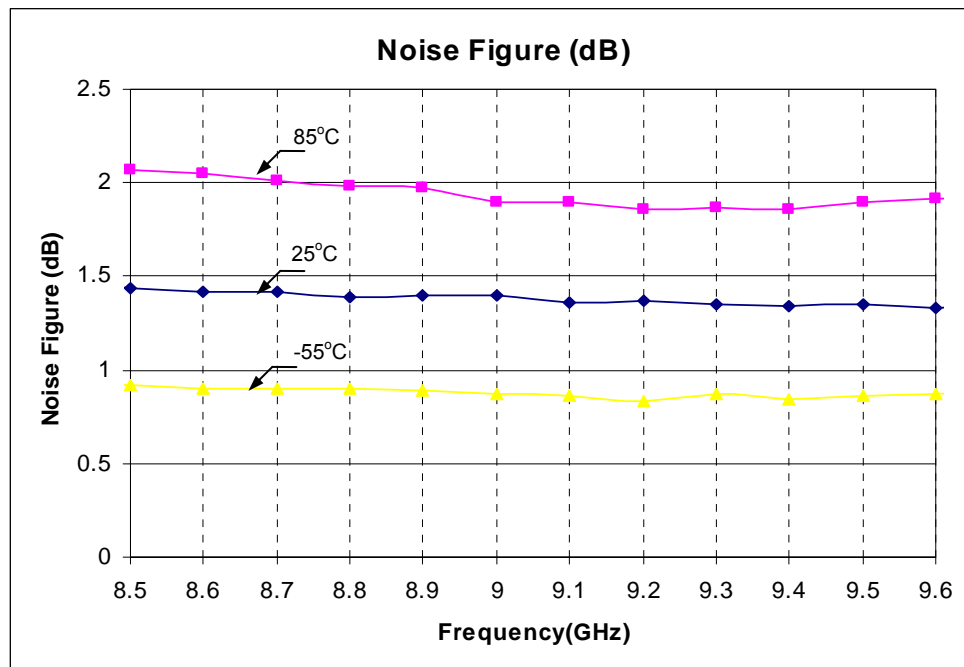
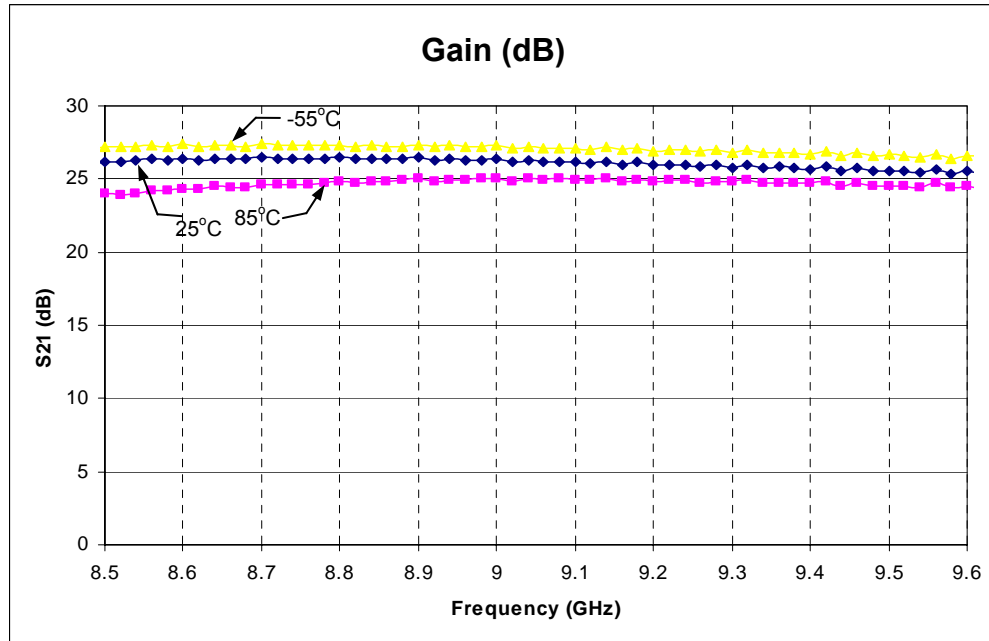
**Test fixture data**

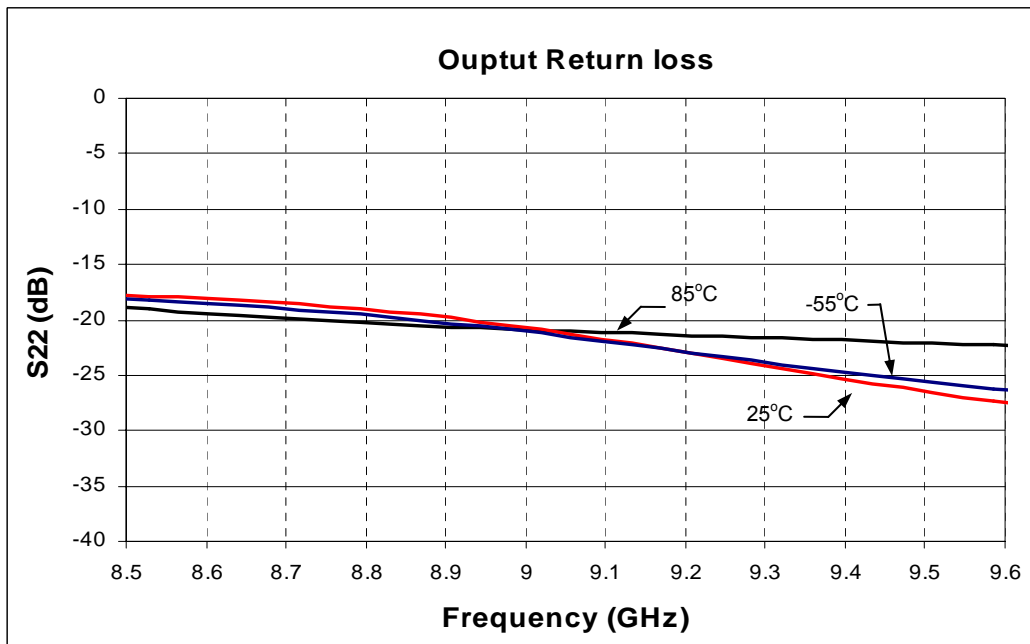
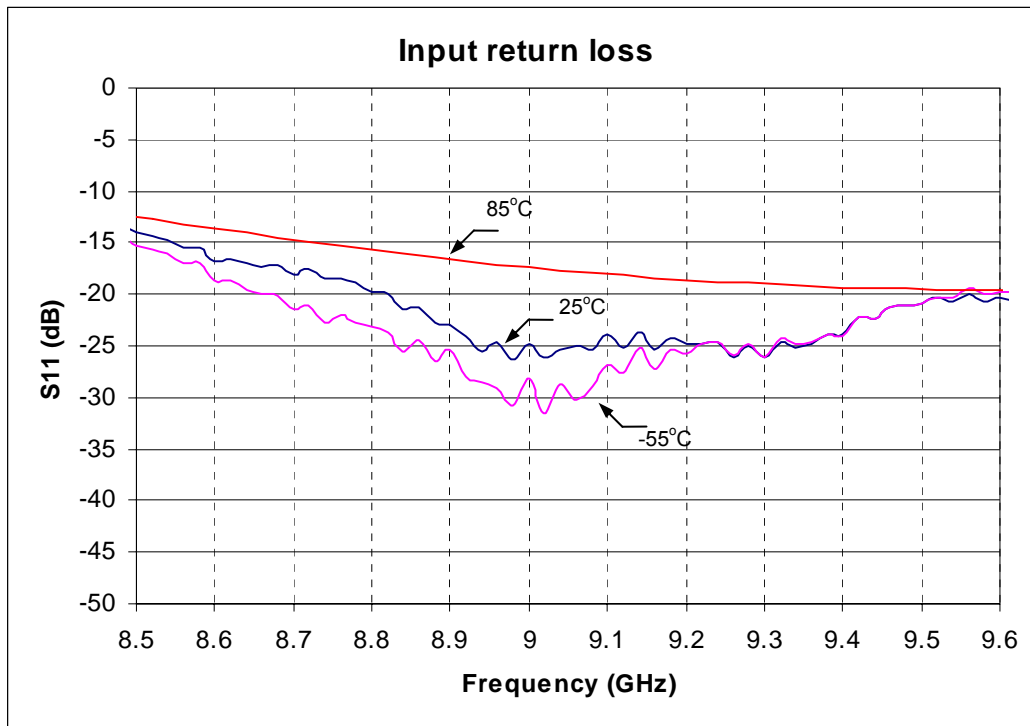
$V_d = 15\text{ V}$ , Current = 80 mA,  $T_A = 25^\circ\text{C}$



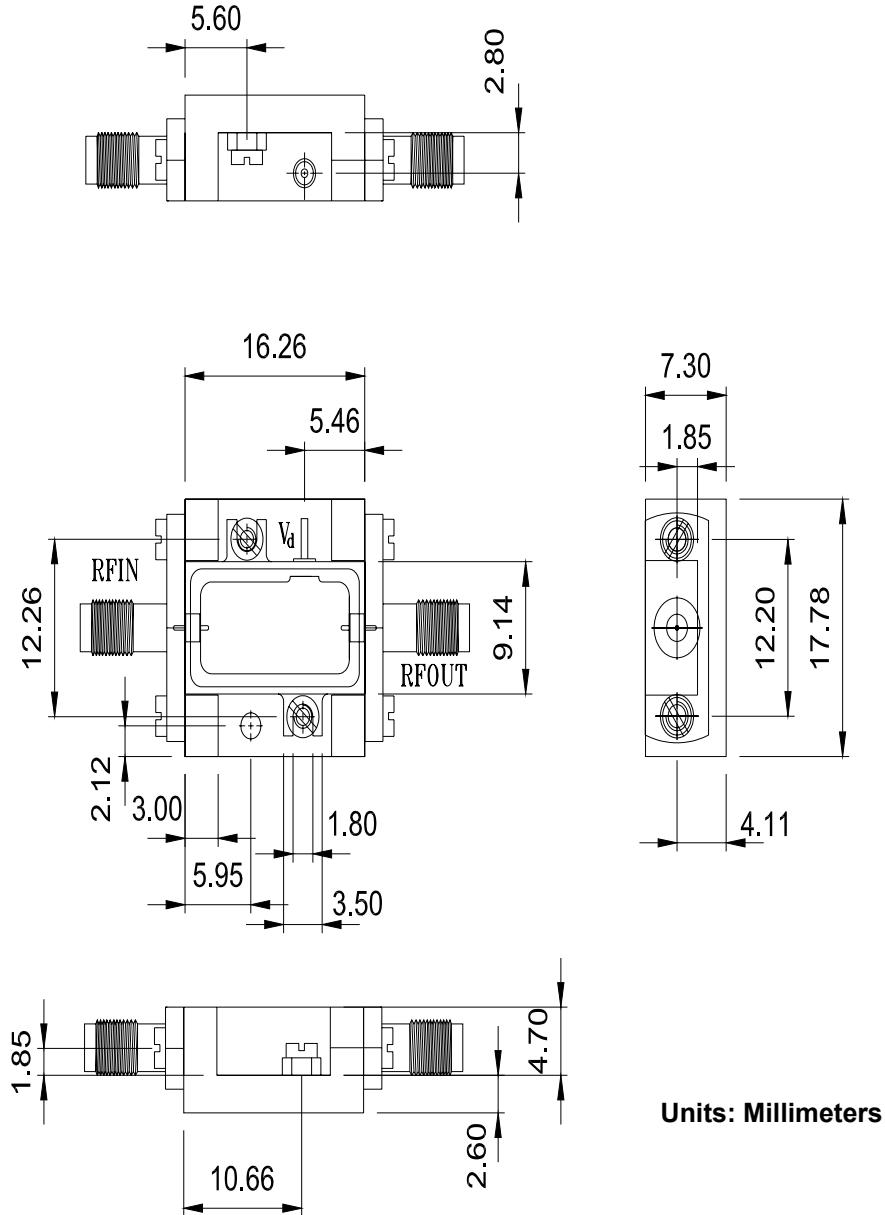
**Test fixture data**
*V<sub>d</sub> = 15 V, Current = 80 mA, T<sub>A</sub> = 25 °C*


**Test fixture data***V<sub>d</sub> = 15 V, Current = 80 mA, T<sub>A</sub> = 25 °C*

**RF Performance over Temperature**
*V<sub>d</sub> = 15 V, Current = 80 mA @ 25°C*


**RF Performance over Temperature**
*V<sub>d</sub> = 15 V, Current = 80 mA @ 25°C*


## Mechanical Characteristics



Units: Millimeters



***GaAs MMIC devices are susceptible to Electrostatic discharge. Proper precautions should be observed during handling, assembly & testing***

All information and Specifications are subject to change without prior notice